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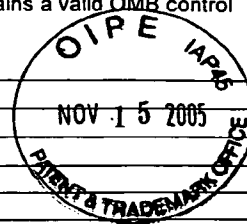
Date Submitted: November 15, 2005

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Sheet 1 of 1

**Complete if Known**

Application Number	Unassigned
Filing Date	10/17/2005
First Named Inventor	Tadahiro OHMI
Group Art Unit	Unassigned
Examiner Name	Unassigned
Attorney Docket Number	039262-0143



**U.S. PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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**FOREIGN PATENT DOCUMENTS**

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		Office <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)				
/T.T./	B1	WO	97/39476		MATSUSHITA ELECTRIC INDUSTRIAL CO., LTD.	03-17-1995		A

**NON PATENT LITERATURE DOCUMENTS**

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/T.T./	B2	M. SATOH, et al., "Rapid Oxidation of SiC Using Microwave-Discharged O <sub>2</sub> Plasma at Low Temperatures (<300°C)," Jap. J. of Applied Physics, Part 2, March 1, 2002, Vol. 41:3A, pp. L233-L235.	

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